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#### Typical Applications

The HMC915LP4E is ideal for:

- PCS / 3G Infrastructure
- Base Stations & Repeaters
- WiMAX & WiBro
- ISM & Fixed Wireless

#### **Functional Diagram**



## GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 0.5 - 2.7 GHz

#### Features

Input IP3: +28 dBm Low Input LO Drive: -2 to +4 dBm High LO to RF Isolation: 28 dB Low Conversion Loss: 8 dB Single Positive Supply: +5V @ 88 mA 24 Lead 4x4mm SMT Package: 16mm<sup>2</sup>

#### **General Description**

The HMC915LP4E is a high linearity, double-balanced converter that operates from 0.5 to 2.7 GHz and delivers a +28 dBm input IP3. The LO amplifier output and high dynamic range mixer input are positioned so that an external LO filter can be placed in series between them if necessary. The converter provides 28 dB of LO to RF isolation and is ideal for upconverter and downconverter applications. The IC operates from a single +5V supply consuming 88 mA and accepts LO drive levels of -2 to +4 dBm. The design requires no external baluns and supports IF frequencies between DC and 1 GHz. The HMC915LP4E is pin for pin compatible with the HMC552LP4E and the HMC215LP4E mixers with integrated LO amplifiers.

#### Electrical Specifications, $T_{A} = +25^{\circ}$ C, LO = +2 dBm, Vcc = +5V, IF = 100 MHz\*

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range, RF, LO		0.5 - 2.0			2.0 - 2.7		GHz
Frequency Range, IF		DC - 1.0			DC - 1.0		GHz
Conversion Loss		8	11		10	13	dB
Noise Figure (SSB)		8.5			10.5		dB
LO to RF Isolation	22	30		25	28		dB
LO to IF Isolation	10	16		12	18		dB
IP3 (Input)		28			28		dBm
1 dB Compression (Input)		18			20		dBm
LO Drive Input Level (Typical)	-2 to 4 +2 to 6		dBm				
Supply Current (Icc)	78	88	110	78	88	110	mA

\*Unless otherwise noted, all measurements performed as a downconverter, with low side LO and configured as shown in application circuit.

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Conversion Gain vs. Temperature, IF = 100 MHz



Isolation



**Return Loss** 



GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 0.5 - 2.7 GHz

Conversion Gain vs.

Temperature, IF = 1 GHz (P) (P)

#### Conversion Gain vs. LO Drive



Upconverter Performance Input IP3 vs. LO Drive



MIXERS - SINGLE & DOUBLE BALANCED - SMT

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## GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 0.5 - 2.7 GHz



#### Input IP3 vs. Temperature, IF = 100 MHz



Input IP3 vs. LO Drive, IF = 100 MHz





Input IP3 vs. Temperature, IF = 1 GHz



Input IP2 vs. Temperature



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### Input IP2 vs. LO Drive



#### Absolute Maximum Ratings

Bias Voltage (Vdd)	5.5 Vdc
RF Power Input	+23 dBm
LO Power Input (Vcc = 5 Vdc)	+10 dBm up to 1 GHz +8 dBm from 1 - 4 GHz
Channel Temperature	150°C
Continuous Pdiss (T = 85°C) (derate 8.4 mW/°C above 85°C)	0.546 W
Thermal Resistance (junction to ground paddle)	119 °C/W
Storage Temperature	-65 to +150°C
Operating Temperature	-55 to +85°C
ESD Sensitivity (HBM)	Class 1C

#### **Typical Supply Current**

Vcc	lcc (mA)
4.5	67 mA
5.0	88 mA
5.5	117 mA



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

### GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 0.5 - 2.7 GHz

#### Input P1dB vs. Temperature



### MxN Spurious @ IF Port

N		nLO				
l	mRF	0	1	2	3	
	0	xx	-3.17	-23.34	-30.34	
Ν	1	-4.67	0.00	-23.67	-52.17	
	2	-76.00	-71.34	-79.84	-71.84	
	3	xx	xx	xx	-74.67	
	4	xx	xx	xx	xx	
	RF Freq. = 1.9 GHz @ -5 dBm					

LO Freq. = 1.8 GHz @ 0 dBm

All values in dBc below the IF output power level.

### Harmonics of LO

	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
1.0	32	40	27	40
1.4	28	19	25	30
1.8	29	16	30	42
2.2	33	18	27	44
2.6	35	23	34	41
3.0	34	20	41	44
LO = 4 dBm				

All values in dBc below input LO level measured at RF port.

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## GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 0.5 - 2.7 GHz

#### **Outline Drawing**



#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[1]</sup>
HMC915LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	<u>H915</u> XXXX

[1] 4-Digit lot number XXXX
[2] Max peak reflow temperature of 260 °C

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### GaAs MMIC MIXER w/ INTEGRATED LO AMPLIFIER, 0.5 - 2.7 GHz



#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1	MIX LO	This pin is DC coupled and matched to 50 Ohms.	
2, 6 - 9, 11 - 17, 19 - 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
3	BIAS	Power supply and output for the LO amplifier. Three external bypass capacitors are recommended for optimum performance, as illustrated in the application circuit.	BIASO
4	GND	Backside of package has exposed metal ground paddle that must also be connected to ground.	⊖ GND 
5	LO	This pin is DC coupled and matched to 50 Ohms. An off chip DC blocking capacitor is required.	LOO
10	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source/sink more than 18 mA of current or die non-function and possible die failure will result.	
18	RF	This pin is DC coupled and matched to 50 Ohms.	

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GaAs MMIC MIXER w/ INTEGRATED

LO AMPLIFIER, 0.5 - 2.7 GHz

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## Application Circuit



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### Evaluation PCB



#### List of Materials for Evaluation PCB 127416 [1]

Item		Description		
J1 - J3		PCB Mount SMA RF Connector		
J4, J5		DC Pin		
C1, C2, C5		100 pF Chip Capacitor, 0402 Pkg.		
C3		1000 pF Chip Capacitor, 0603 Pkg.		
C4		2.2 µF Capacitor, Tantalum		
L1		24 nH Chip Inductor, 0603 Pkg.		
R1		1.8 Ohm Resistor, 1206 ¼ Watt Pkg.		
U1 HI		HMC915LP4E		
PCB [2]		113417 Evaluation PCB		

 $\left[ 1\right]$  Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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